

Descriptions

N-channel Double MOSFET in a SOT23-6 Plastic Package.

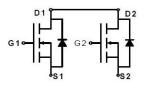
Features

advanced trench technology to provide excellent $R_{DS(on)}$, low gate charge and operation with gate voltages as low as 2.5V.

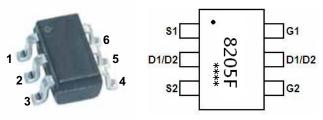
Applications

Use as a Battery protection , Switching application.

Equivalent Circuit



Pinning



Marking

Marking

2018-06/33 REV:O

Absolute Maximum Ratings(Ta=25 °C)

Parameter	Symbol	Rating	Unit
Drain-Source Voltage	V _{DS}	20	V
Drain Current - Continuous	I _D (Ta=25℃)	6.0	A
Drain Current - Continuous	I _D (Ta=100℃)	4.8	А
Drain Current – Pulsed	I _{DM}	20	А
Gate-Source Voltage	V _{GS}	±12	V
Maximum Power Dissipation	P _D (Ta=25℃)	1.14	W
Thermal Resistance Junction-to-Ambient	R _{0JA}	110	°C/W
Junction Temperature	Tj	150	°C
Storage Temperature Range	T _{stg}	-55 ~ 150	°C

Electrical Characteristics(Ta=25°C)

Parameter	Symbol	Test Conditions		Min	Тур	Max	Unit
Drain-Source Breakdown Voltage	BV_{DSS}	V _{GS} =0V	I _D =250μΑ	20			V
Drain-Source Leakage Current(T _i =25℃)	I _{DSS}	V _{DS} =20V	V _{GS} =0V			1	μA
Drain-Source Leakage Current(T _i =70℃)	I _{DSS}	V _{DS} =16V	V _{GS} =0V			25	μA
Gate-Source Leakage Current	I_{GSS}	V _{GS} =±10V	V _{DS} =0V			±100	nA
Gate Threshold Voltage	V _{GS(th)}	$V_{DS}=V_{GS}$	I _D =250μΑ	0.5		1.2	V
Static Drain-Source On-Resistance	RDS(on)	V _{GS} =4.5V	I _D =1.0A		11.5	17	mΩ
		V _{GS} =2.5V	I _D =1.0A		16.5	22	mΩ
		V _{GS} =4.5V	I _D =6.0A		14	20	mΩ
		V _{GS} =2.5V	I _D =5.2A		17	24	mΩ
Forward Transconductance	g fs	V _{DS} =5.0V	I _D =4.0A	5			S
Forward On Voltage	V_{SD}	V _{GS} =0V	I _S =1.7A			1.2	V
Input Capacitance	C _{iss}				1035		pF
Output Capacitance	C _{oss}	V _{DS} =20V V _{GS} =0V f=1.0MHz			320		pF
Reverse Transfer Capacitance	C _{rss}	1 1.010112			150		pF
Turn-on Delay Time	t _{d(on)}		I _D =1A R _G =6Ω		30		ns
Rise Time	t _r	V _{DS} =10V V _{GS} =5V R _D =10Ω			70		ns
Turn-off Delay Time	t _{d(off)}				40		ns
Fall Time	t _f				65		ns

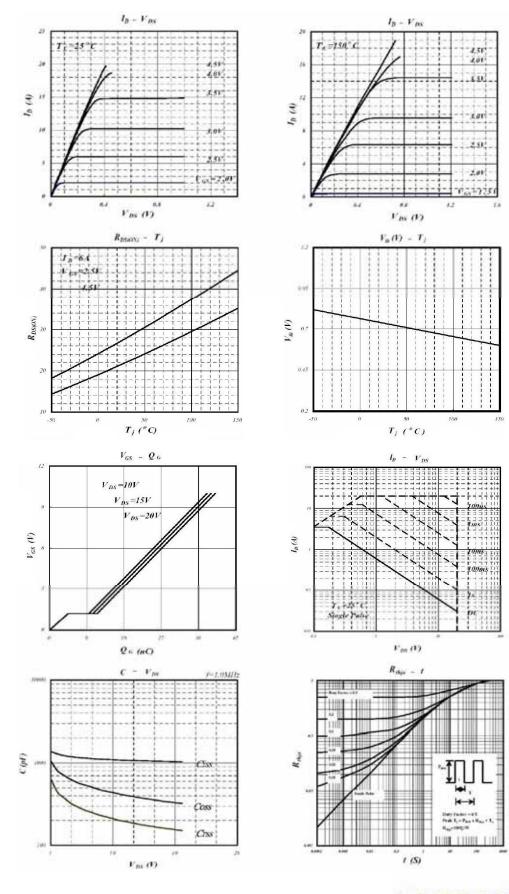
Notes:

1, Surface Mounted on FR4 Board, $t \le 10$ sec.

2 Pulse Test: Pulse Width \leq 300µs, Duty Cycle \leq 2%.

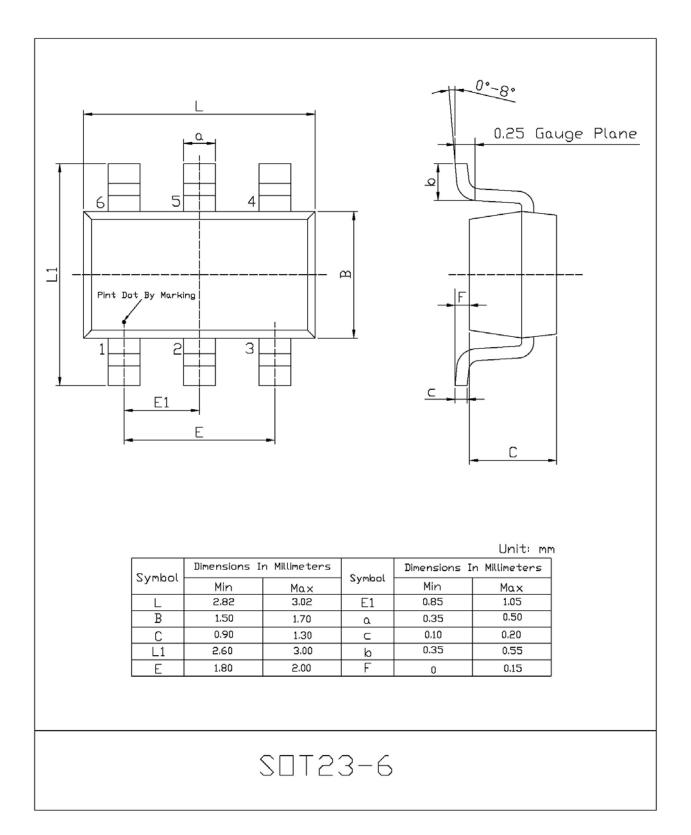
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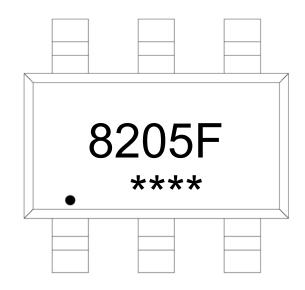
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Package Dimensions



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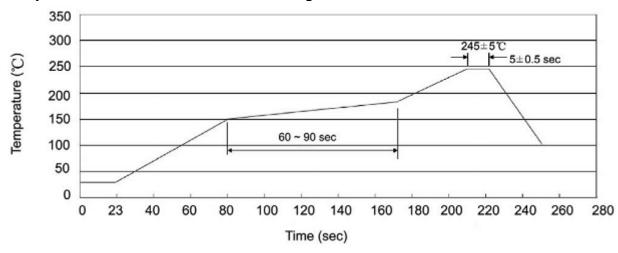
Marking Instructions





8205F: Product Type Code.****: Date code change with manufacturing date.





Temperature Profile for IR Reflow Soldering(Pb-Free)

Notes:

1.Preheating:25~150 °C, Time:60~90sec.

2.Peak Temp.:245 ±5°C, Duration:5±0.5sec.

3. Cooling Speed: 2~10°C/sec.

Resistance to Soldering Heat Test Conditions

Temp:260±5℃ Time:10±1 sec

Packaging SPEC.

REEL

Package Type	Units				Dimension		(unit: mm ³)	
i donago i jpo	Units/Reel	Reels/Inner Box	Units/Inner Box	Inner Boxes/Outer Box	Units/Outer Box	Reel	Inner Box	Outer Box
SOT23-5/6	3,000	10	30,000	4	120,000	7″×8	210×205×205	445×230×435



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